

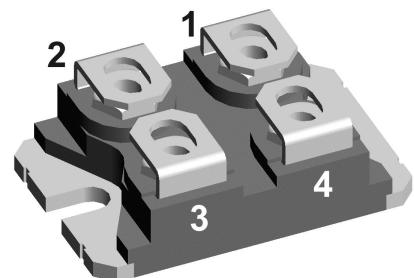
FRED

V_{RRM} = 600 V
 I_{FAV} = 2x 30 A
 t_{rr} = 35 ns

Fast Recovery Epitaxial Diode
Low Loss and Soft Recovery
Parallel legs

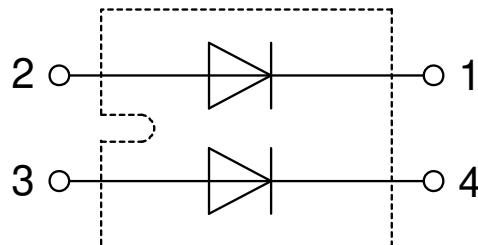
Part number

DSEI2x31-06C



Backside: isolated

 E72873



Features / Advantages:

- Planar passivated chips
- Low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low I_{rm} -values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low I_{rm} reduces:
 - Power dissipation within the diode
 - Turn-on loss in the commutating switch

Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

Package: SOT-227B (minibloc)

- Isolation Voltage: 3000 V~
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Base plate: Copper internally DCB isolated
- Advanced power cycling

Disclaimer Notice

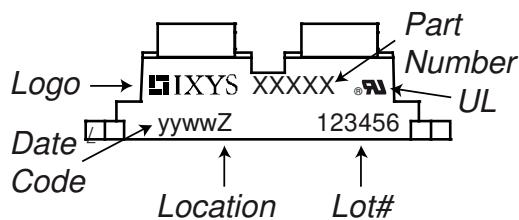
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Fast Diode

Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	
V_{RSM}	max. non-repetitive reverse blocking voltage	$T_{VJ} = 25^\circ\text{C}$			600	V
V_{RRM}	max. repetitive reverse blocking voltage	$T_{VJ} = 25^\circ\text{C}$			600	V
I_R	reverse current, drain current	$V_R = 600 \text{ V}$ $V_R = 480 \text{ V}$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$		100 7	μA mA
V_F	forward voltage drop	$I_F = 30 \text{ A}$ $I_F = 60 \text{ A}$ $I_F = 30 \text{ A}$ $I_F = 60 \text{ A}$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 150^\circ\text{C}$		1.51 1.68 1.34 1.60	V V
I_{FAV}	average forward current	$T_C = 90^\circ\text{C}$ rectangular $d = 0.5$	$T_{VJ} = 150^\circ\text{C}$		30	A
V_{F0} r_F	threshold voltage slope resistance } for power loss calculation only		$T_{VJ} = 150^\circ\text{C}$		1.10 7.9	V $\text{m}\Omega$
R_{thJC}	thermal resistance junction to case				1.2	K/W
R_{thCH}	thermal resistance case to heatsink			0.10		K/W
P_{tot}	total power dissipation		$T_C = 25^\circ\text{C}$		105	W
I_{FSM}	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}; V_R = 0 \text{ V}$	$T_{VJ} = 45^\circ\text{C}$		300	A
C_J	junction capacitance	$V_R = 600 \text{ V}$ $f = 1 \text{ MHz}$	$T_{VJ} = 25^\circ\text{C}$		22	pF
I_{RM}	max. reverse recovery current		$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 100^\circ\text{C}$		5.5 9	A A
t_{rr}	reverse recovery time	$I_F = 37 \text{ A}; V_R = 350 \text{ V}$ $-di_F/dt = 200 \text{ A}/\mu\text{s}$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 100^\circ\text{C}$		80 150	ns ns

Package SOT-227B (minibloc)			Ratings		
Symbol	Definition	Conditions	min.	typ.	max.
		per terminal			Unit
I_{RMS}	RMS current	per terminal			70 A
T_{VJ}	virtual junction temperature		-40		150 °C
T_{op}	operation temperature		-40		125 °C
T_{stg}	storage temperature		-40		150 °C
Weight				30	g
M_D	mounting torque		1.1		1.5 Nm
M_T	terminal torque		1.1		1.5 Nm
$d_{Spp/App}$	creepage distance on surface / striking distance through air		terminal to terminal	10.5	3.2 mm
$d_{Spb/Apb}$			terminal to backside	8.6	6.8 mm
V_{ISOL}	isolation voltage	t = 1 second t = 1 minute	50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA		3000 V 2500 V

Product Marking

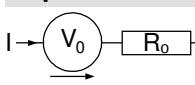


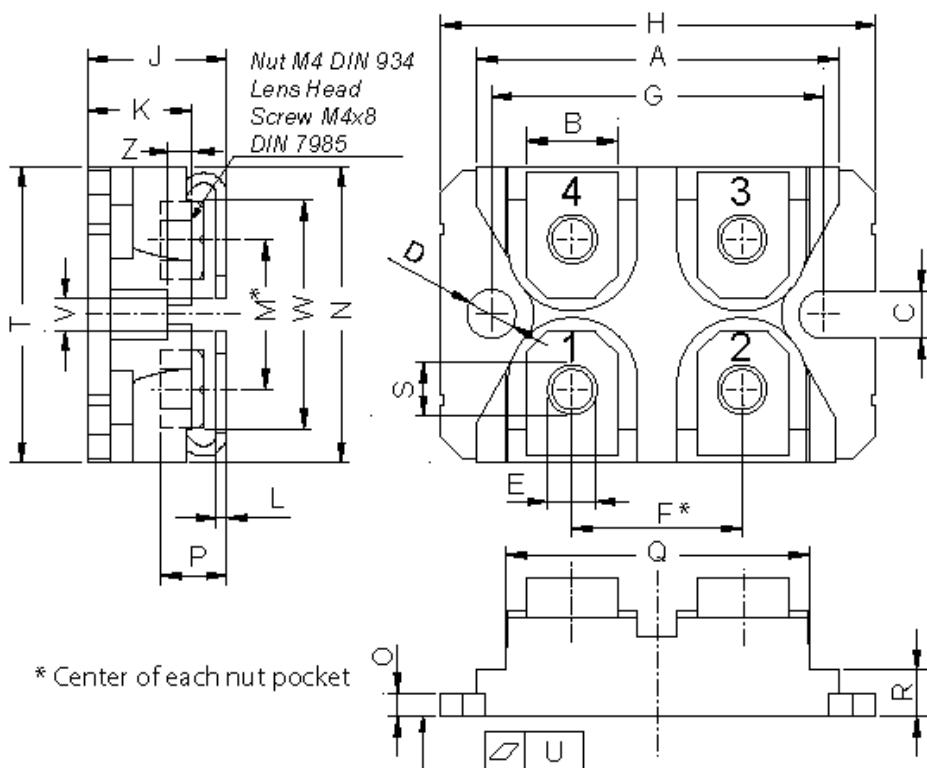
Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSEI2x31-06C	DSEI2x31-06C	Tube	10	456438

Similar Part	Package	Voltage class
DSEI2x30-06C	SOT-227B (minibloc)	600

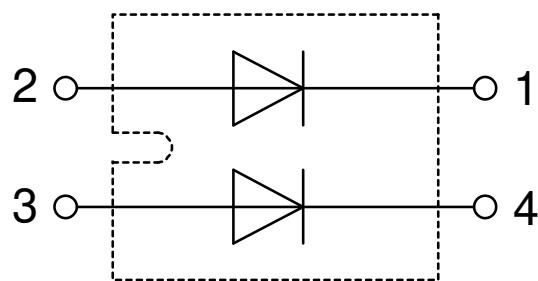
Equivalent Circuits for Simulation

* on die level
 $T_{VJ} = 150^\circ\text{C}$

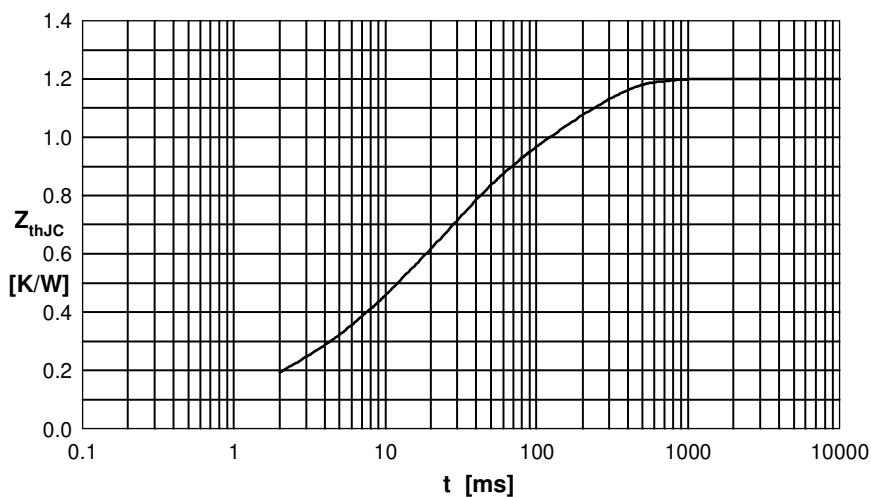
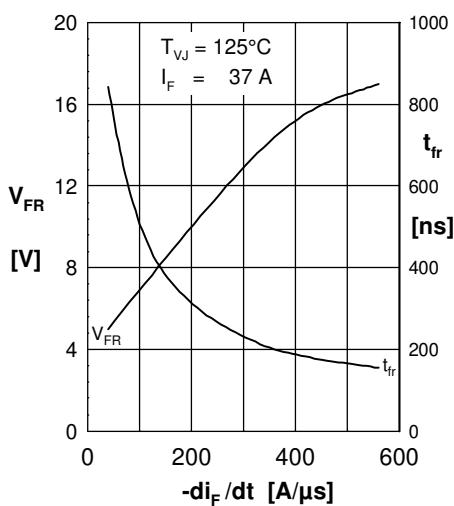
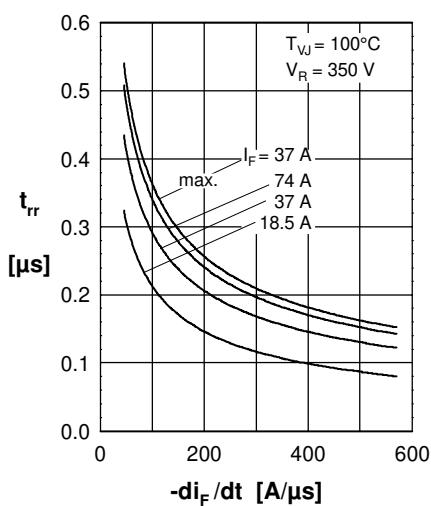
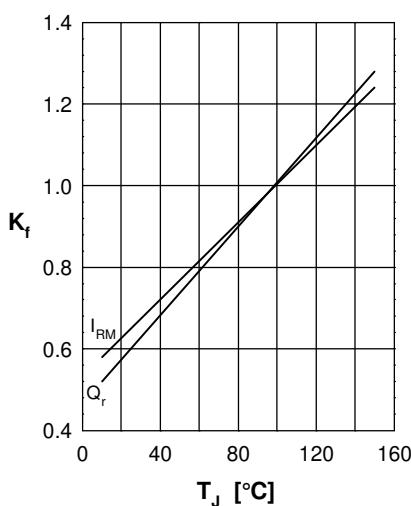
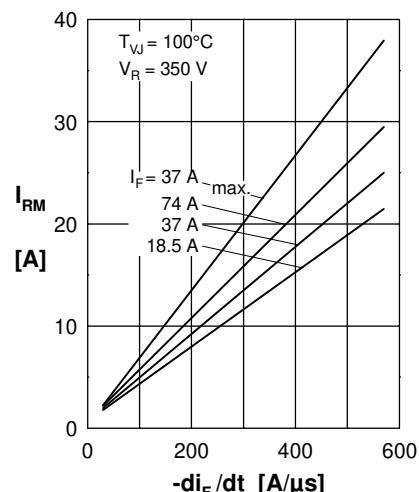
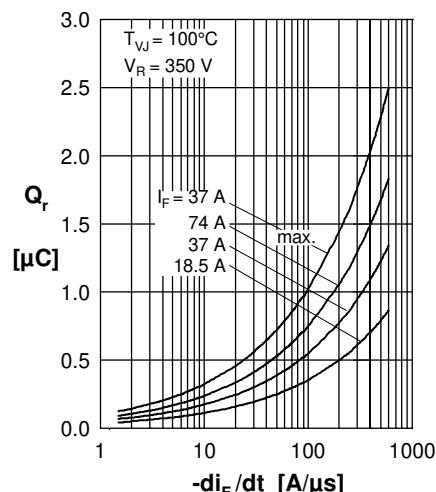
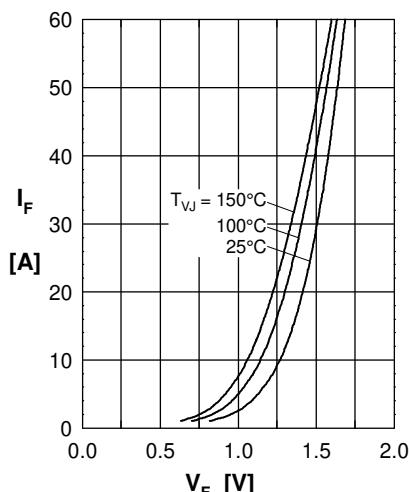
	Fast Diode	
$V_{0\ max}$	threshold voltage	1.1 V
$R_{0\ max}$	slope resistance *	6 mΩ

Outlines SOT-227B (minibloc)


Dim.	Millimeter		Inches	
	min	max	min	max
A	31.50	31.88	1.240	1.255
B	7.80	8.20	0.307	0.323
C	4.09	4.29	0.161	0.169
D	4.09	4.29	0.161	0.169
E	4.09	4.29	0.161	0.169
F	14.91	15.11	0.587	0.595
G	30.12	30.30	1.186	1.193
H	37.80	38.23	1.488	1.505
J	11.68	12.22	0.460	0.481
K	8.92	9.60	0.351	0.378
L	0.74	0.84	0.029	0.033
M	12.50	13.10	0.492	0.516
N	25.15	25.42	0.990	1.001
O	1.95	2.13	0.077	0.084
P	4.95	6.20	0.195	0.244
Q	26.54	26.90	1.045	1.059
R	3.94	4.42	0.155	0.167
S	4.55	4.85	0.179	0.191
T	24.59	25.25	0.968	0.994
U	-0.05	0.10	-0.002	0.004
V	3.20	5.50	0.126	0.217
W	19.81	21.08	0.780	0.830
Z	2.50	2.70	0.098	0.106



Fast Diode



Constants for Z_{thJC} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.180	0.0050
2	0.020	0.0600
3	0.100	0.0010
4	0.400	0.1700
5	0.500	0.0230